

SE3401B

-2.8A,-20V P-Channel MOSFET

Revision:A

General Description

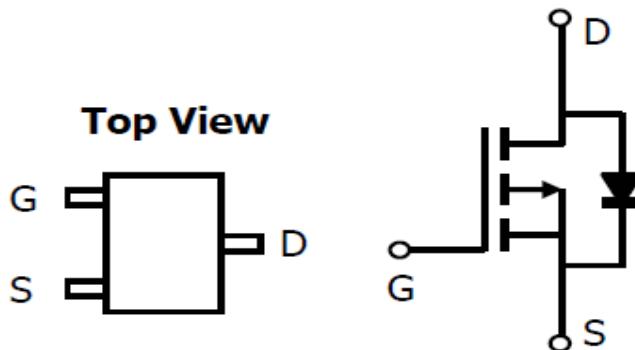
The MOSFETs from SINO-IC provide the best combination of fast switching, low on-resistance and cost-effectiveness.

Features

- V_{DS} (V) = -20V I_D = -2.8A
- $R_{DS(ON)} < 120\text{m}\Omega$ ($V_{GS} = -4.5\text{V}$)
- $R_{DS(ON)} < 170\text{m}\Omega$ ($V_{GS} = -2.5\text{V}$)

Pin configurations

See Diagram below

**Absolute Maximum Ratings**

Parameter		Symbol	Rating	Units
Drain-Source Voltage		V_{DS}	-20	V
Gate-Source Voltage		V_{GS}	± 12	V
Drain Current (Note 1)	Continuous	I_D	-2.8	A
	70°C		-2.2	
Total Power Dissipation		P_D	1.4	W
Operating Junction Temperature Range		T_J	-50 to 150	°C

Thermal Characteristics

Parameter		Symbol	Typ	Max	Units
Maximum Junction-to-Ambient	A	$R_{\theta JA}$	65	90	°C/W
Maximum Junction-to-- Case	Steady-State	$R_{\theta JC}$	0.8	-	°C/W

Electrical Characteristics (T_J=25°C unless otherwise noted)						
Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
OFF/ON CHARACTERISTICS (Note 2)						
BV _{DSS}	Drain-Source Breakdown Voltage	I _D =-250 μ A, V _{GS} =0 V	-20			V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =-24 V, V _{GS} =0 V			-1	μ A
I _{CSS}	Gate-Body leakage current	V _{DS} =0 V, V _{GS} =±12 V			±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} I _D =-250 μ A	-0.4	-0.7	-1.1	V
R _{DSON}	Static Drain-Source On-Resistance ²	V _{GS} =-4.5V, I _D =-2.8A	-	92	120	mΩ
		V _{GS} =-2.5V, I _D =-2A		130	170	mΩ
V _{SD}	Diode Forward Voltage	V _{GS} =0V, I _D =-1A	-	-0.7	-1	V
DYNAMIC PARAMETERS						
C _{iss}	Input Capacitance	V _{GS} =0V, V _{DS} =-15V, f=1MHz		850		pF
C _{oss}	Output Capacitance			105		pF
C _{rss}	Reverse Transfer Capacitance			68		pF
T _{ON}	Turn-On Time	V _{DS} = -15V, R _L = 3.6 Ω , R _{GEN} = 6 Ω , V _{GS} = -10 V	-	9.5		ns
T _{OFF}	Turn-Off Time		-	36		ns
T _r	Turn-on Rise Time		-	3.0		ns
T _f	Turn-on Fall Time		-	5.2		ns
Q _g	Total Gate Charge	V _{DS} = -4.5V, I _D = -4A, V _{GS} = -15V		7.3		nC
Q _{gs}	Gate-Source Charge			2.2		nC
Q _{gd}	Gate-Drain Charge			2		nC
t _{rr}	Body Diode Reverse Recovery Time	I _F =-4A, dI/dt=100A/μ s		20.2		ns
Q _{rr}	Body Diode Reverse Recovery Charge	I _F =-4A, dI/dt=100A/μ s		11.2		nC

Typical Characteristics

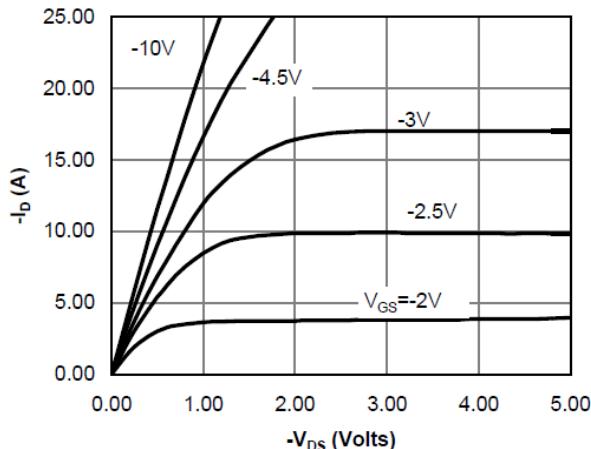


Fig 1: On-Region Characteristics

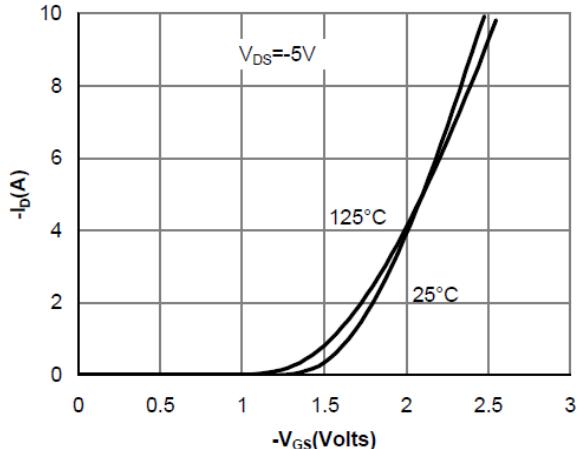


Figure 2: Transfer Characteristics

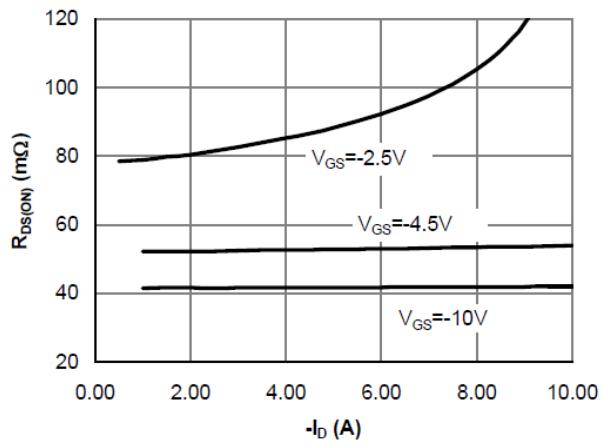


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

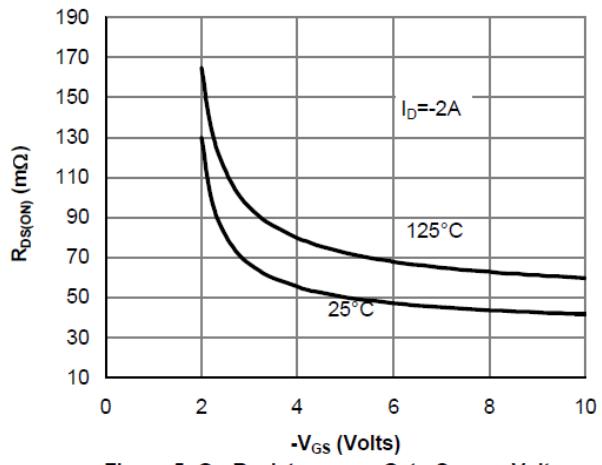
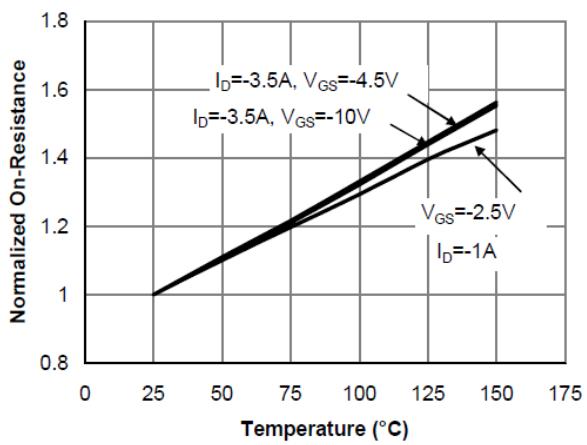


Figure 5: On-Resistance vs. Gate-Source Voltage

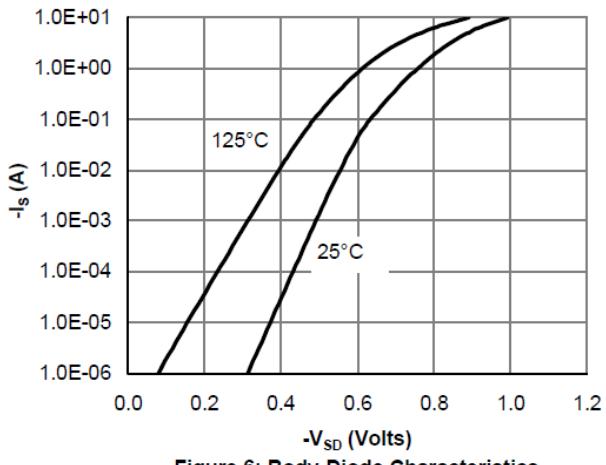
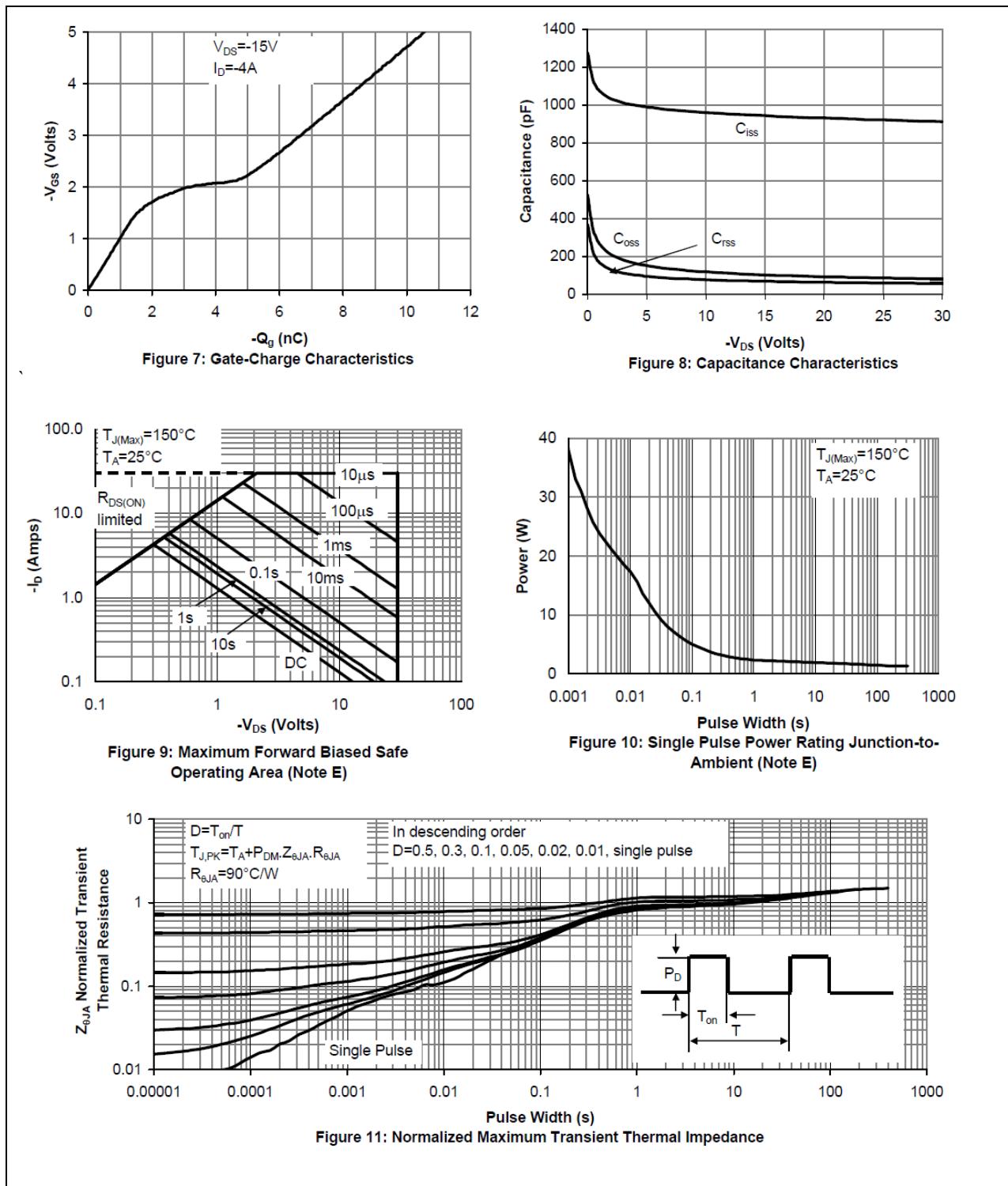
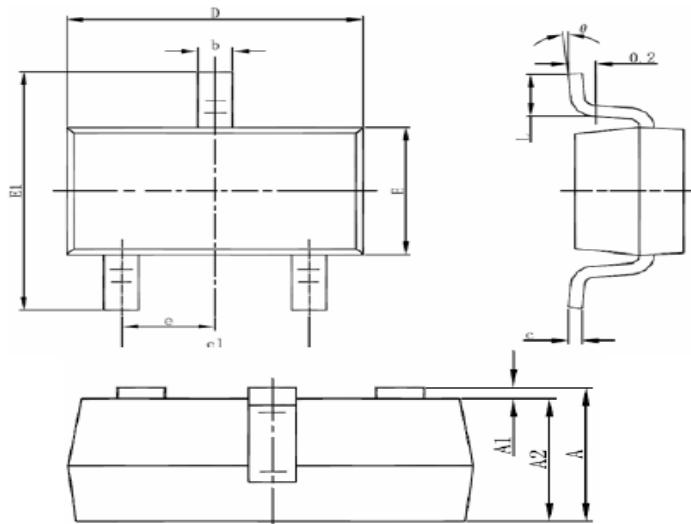


Figure 6: Body-Diode Characteristics



SOT-23-3L Package Information

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

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